



isc Silicon NPN Power Transistor

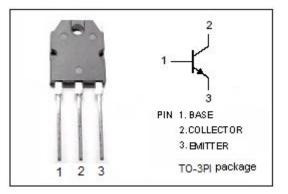
2SC3181

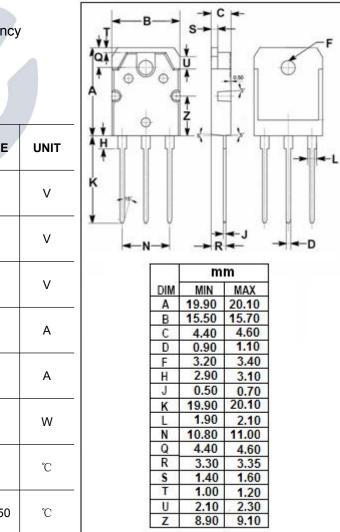
DESCRIPTION

- Low Collector Saturation Voltage-: V_{CE(sat)}= 2.0V(Max.) @I_C= 6A
- · Good Linearity of hFE
- Complement to Type 2SA1264
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Power amplifier applications
- Recommend for 55W high fidelity audio frequency amplifier output stage applications





ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	120	V
V _{CEO}	Collector-Emitter Voltage	120	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	8	A
I _B	Base Current-Continuous	0.8	A
Pc	Collector Power Dissipation @ T_C =25°C	80	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C



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ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V(BR)CEO	Collector-Emitter Breakdown Voltage	I _C = 50mA; I _B = 0	120			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 0.6A			2.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 4A; V _{CE} = 5V			1.5	V
Ісво	Collector Cutoff Current	V _{CB} = 120V; I _E = 0			5	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			5	μA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	55		160	
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 5V	35			
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		190		pF
fT	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 5V		30		MHz

h_{FE-1} Classifications

R	ο	
55-110	80-160	

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